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**PALM INTRANET**

## Inventor Name Search Result

Your Search was:

Last Name = MORITA

First Name = ETSUO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<a href="#">08070204</a>	5418374	150	06/02/1993	SEMICONDUCTOR DEVICE HAVING AN ACTIVE LAYER WITH REGIONS WITH DIFFERENT BANDGAPS	MORITA, ETSUO
<a href="#">08389790</a>	Not Issued	166	02/16/1995	SEMICONDUCTOR LIGHT EMITTING DEVICE	MORITA, ETSUO
<a href="#">08561865</a>	5705421	150	11/22/1995	A SOI SUBSTRATE FABRICATING METHOD	MORITA, ETSUO
<a href="#">08691536</a>	5665977	250	08/02/1996	SEMICONDUCTOR LIGHT EMITTING DEVICE WITH DEFECT DECOMPOSING AND BLOCKING LAYERS	MORITA, ETSUO
<a href="#">08769708</a>	5821568	150	12/18/1996	CLEAVED SEMICONDUCTOR DEVICE WITH {11-20} PLANE	MORITA, ETSUO
<a href="#">08772066</a>	5753966	150	12/19/1996	SEMICONDUCTOR DEVICE WITH CLEAVED SURFACE	MORITA, ETSUO
<a href="#">08826108</a>	5828086	250	03/24/1997	SEMICONDUCTOR LIGHT EMITTING DEVICE WITH A MG SUPERLATTICE STRUCTURE	MORITA, ETSUO
<a href="#">09059827</a>	6107162	150	04/14/1998	Method for Manufactured of Cleaved Light Emitting Semiconductor Device	MORITA, ETSUO
<a href="#">09072177</a>	6121636	150	05/05/1998	SEMICONDUCTOR LIGHT EMITTING DEVICE	MORITA, ETSUO
<a href="#">09088743</a>	6501154	150	06/02/1998	SEMICONDUCTOR SUBSTRATE MADE OF A NITRIDE III-V COMPOUND SEMICONDUCTOR HAVING A WURTZITE-STRUCTURE CRYSTAL STRUCTURE	MORITA, ETSUO
<a href="#">09334666</a>	6232623	150	06/17/1999	SEMICONDUCTOR DEVICE ON A SAPPHIRE SUBSTRATE	MORITA, ETSUO

<u>09360624</u>	Not Issued	161	07/26/1999	ELECTRODE, SEMICONDUCTOR DEVICE AND METHODS FOR MAKING THEM	MORITA, ETSUO
<u>09726860</u>	Not Issued	71	11/30/2000	Method of manufacturing crystal of III-V compound of the nitride system, crystal substrate of III-V compound of the nitride system, crystal film of III-V compound of the nitride system, and method of manufacturing device	MORITA, ETSUO
<u>09728193</u>	Not Issued	41	11/30/2000	Method of manufacturing crystal of III-V compound of the nitride system, crystal substrate of III-V compound of the nitride system, crystal film of III-V compound of the nitride system, and method of manufacturing device	MORITA, ETSUO
<u>09739491</u>	<u>6498048</u>	150	12/18/2000	METHOD OF MANUFACTURING CRYSTAL OF III-V COMPOUNDS OF THE NITRIDE SYSTEM, CRYSTAL SUBSTRATE OF III-V COMPOUNDS OF THE NITRIDE SYSTEM, CRYSTAL FILM OF III-V COMPOUNDS OF THE NITRIDE SYSTEM, AND METHOD OF MANUFACTURING DEVICE	MORITA, ETSUO
<u>09795844</u>	Not Issued	94	02/28/2001	METHOD OF CRYSTALLIZING A NITRIDE III-V COMPOUND SEMICONDUCTOR LAYER ON A SAPPHIRE SUBSTRATE	MORITA, ETSUO
<u>10118097</u>	Not Issued	161	04/08/2002	Electrode, semiconductor device and methods for making them	MORITA, ETSUO
<u>10290570</u>	<u>6727523</u>	150	11/08/2002	METHOD OF MANUFACTURING CRYSTAL OF III-V COMPOUNDS OF THE NITRIDE SYSTEM, CRYSTAL SUBSTRATE OF III-V COMPOUNDS OF THE NITRIDE SYSTEM, CRYSTAL FILM OF III-V COMPOUNDS OF THE NITRIDE SYSTEM, AND METHOD OF MANUFACTURING DEVICE	MORITA, ETSUO
<u>10341706</u>	<u>6967353</u>	150	01/14/2003	SEMICONDUCTOR LIGHT EMITTING DEVICE AND	MORITA, ETSUO

				FABRICATION METHOD THEREOF	
<u>10466607</u>	Not Issued	40	11/20/2003	Crystal film, crystal substrate, and semiconductor device	MORITA, ETSUO
<u>11113597</u>	Not Issued	30	04/25/2005	Method of crystallizing a nitride III-V compound semiconductor layer on a sapphire substrate	MORITA, ETSUO

**Inventor Search Completed: No Records to Display.**

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